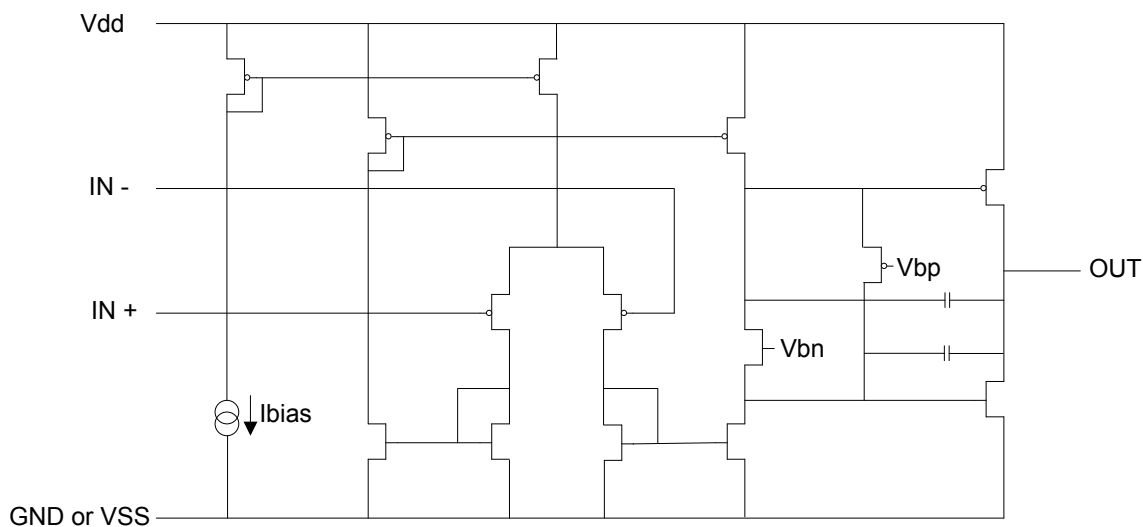


Simplified Schematic Diagram



Pin Descriptions

Pin Number		TLV271		TLV272	
SOT25	SO-8/ MSOP-8	Pin Name	Function	Pin Name	Function
	1	N/C	No connection	1OUT	Output op-amp 1
4	2	IN-	Inverting input	1IN-	Inverting input op-amp 1
3	3	IN+	Non-inverting input	1IN+	Non-inverting input op-amp 1
2	4	GND	Ground	GND	Ground
	5	N/C	No connection	2IN+	Non inverting input op-amp 2
1	6	OUT	Output	2IN-	Inverting input op-amp 2
5	7	V _{DD}	Supply	2OUT	Output op-amp 2
	8	N/C	No connection	V _{DD}	Supply

Absolute Maximum Ratings (Note 4)

Symbol	Parameter		Rating	Unit
V_{DD}	Supply Voltage: (Note 5)		16.5	V
V_{ID}	Differential Input Voltage		$\pm V_{DD}$	V
V_{IN}	Input Voltage Range (Note 5)		-0.2 to $V_{DD} + 0.2V$	V
I_{IN}	Input Current Range		± 10	mA
I_O	Output Current Range		± 100	mA
P_D	Power Dissipation (Note 6)	TLV271 SOT25	220mW	mW
		TLV271 SO-8	396mW	
		TLV272 SO-8	396mW	
		TLV272 MSOP-8	300mW	
T_A	Operating Temperature Range	C grade	0 to +70	°C
		I grade	-40 to +125	
T_J	Operating Junction Temperature		150	°C
T_{ST}	Storage Temperature Range		-65 to +150	°C
ESD HBM	Human Body Model ESD Protection (1.5k Ω in series with 100pF)		2	kV
ESD MM	Machine Model ESD Protection		150	V

- Notes:
- Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
 - All voltage values, except differential voltages, are with respect to ground.
 - For operating at high temperatures, the TLV27x must be derated to zero based on a +150°C maximum junction temperature and a thermal resistance as below when the device is soldered to a printed circuit board, operating in a still air ambient:

Package	θ_{JA}	Unit
SOT25	180	°C/W
SO-8	150	
MSOP-8	155	

Recommended Operating Conditions

Symbol	Parameter		C grade		I grade		Unit
			Min	Max	Min	Max	
V_{DD}	Supply Voltage	Single Supply	2.7	16	2.7	16	V
		Split Supply	± 1.35	± 8	± 1.35	± 8	
V_{IC}	Common Mode Input Voltage		0	$V_{DD} - 1.35$	0	$V_{DD} - 1.35$	V
T_A	Operating Free Air Temperature		0	+70	-40	+125	°C

Electrical Characteristics (@T_A = +25°C and V_{DD} = 2.7V, 5V, ±5V unless otherwise specified.)

DC Performance								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
V _{IO}	Input Offset Voltage	V _{IC} = V _{DD} /2, V _O = V _{DD} /2, R _S = 50Ω, R _L = 10kΩ		+25°C	—	0.5	5	mV
				-40°C to +125°C	—	—	7	
α _{VIO}	Offset Voltage Drift			+25°C	—	6	—	μV/°C
A _{VD}	Large Signal Differential Voltage Gain	V _{O(PP)} = V _{DD} /2, R _L = 10kΩ	V _{DD} = 2.7V	+25°C	97	106	—	dB
				-40°C to +125°C	76	—	—	
			V _{DD} = 5V	+25°C	100	110	—	
				-40°C to +125°C	86	—	—	
				V _{DD} = ±5V	+25°C	100	115	
-40°C to +125°C	90	—	—					
CMRR	Common Mode Rejection Ratio	V _{IC} = 0 to V _{DD} -1.35V, R _S = 50Ω	V _{DD} = 2.7V	+25°C	58	70	—	dB
				-40°C to +125°C	55	—	—	
			V _{DD} = 5V	+25°C	65	80	—	
				-40°C to +125°C	62	—	—	
		V _{IC} = -5 to V _{DD} -1.35V, R _S = 50Ω	V _{DD} = ±5V	+25°C	69	85	—	
-40°C to +125°C	66	—		—				
Input Characteristics								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
I _{IO}	Input Offset Current	V _{DD} = 5V, V _{IC} = V _{DD} /2, V _O = V _{DD} /2, R _S = 50Ω		+25°C	—	1	60	pA
				+70°C	—	—	100	
				+125°C	—	—	1000	
I _{IB}	Input Bias Current			+25°C	—	1	60	
				+70°C	—	—	100	
				+125°C	—	—	1000	
r _{i(d)}	Differential Input Resistance	—		+25°C	—	100	—	MΩ
C _{IC}	Common Mode Input Capacitance	f = 21kHz		+25°C	—	12	—	pF

Electrical Characteristics (cont.) (@T_A = +25°C and V_{DD} = 2.7V, 5V, ±5V unless otherwise specified.)

Output Characteristics								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
V _{OH}	High Level Output Voltage	V _{IC} = V _{DD} /2, I _{OH} = -1mA	V _{DD} = 2.7V	+25°C	2.55	2.58	—	V
				-40°C to +125°C	2.48	—	—	
			V _{DD} = 5V	+25°C	4.9	4.93	—	
				-40°C to +125°C	4.85	—	—	
			V _{DD} = ±5V	+25°C	4.92	4.96	—	
				-40°C to +125°C	4.9	—	—	
		V _{IC} = V _{DD} /2, I _{OH} = -5mA	V _{DD} = 2.7V	+25°C	1.9	2.1	—	
				-40°C to +125°C	1.5	—	—	
			V _{DD} = 5V	+25°C	4.6	4.68	—	
				-40°C to +125°C	4.5	—	—	
			V _{DD} = ±5V	+25°C	4.7	4.84	—	
				-40°C to +125°C	4.65	—	—	
V _{OL}	Low Level Output Voltage	V _{IC} = V _{DD} /2, I _{OL} = 1mA	V _{DD} = 2.7V	+25°C	—	0.1	0.15	V
				-40°C to +125°C	—	—	0.22	
			V _{DD} = 5V	+25°C	—	0.05	0.1	
				-40°C to +125°C	—	—	0.15	
			V _{DD} = ±5V	+25°C	—	-4.95	-4.92	
				-40°C to +125°C	—	—	-4.9	
		V _{IC} = V _{DD} /2, I _{OL} = 5mA	V _{DD} = 2.7V	+25°C	—	0.5	0.7	
				-40°C to +125°C	—	—	1.1	
			V _{DD} = 5V	+25°C	—	0.28	0.4	
				-40°C to +125°C	—	—	0.5	
			V _{DD} = ±5V	+25°C	—	-4.84	-4.7	
				-40°C to +125°C	—	—	-4.65	
I _O	Output Current	V _O = 0.5V from rail, V _{DD} = 2.7V	Positive rail	+25°C	—	4	—	mA
			Negative rail	+25°C	—	5	—	
		V _O = 0.5V from rail, V _{DD} = 5V	Positive rail	+25°C	—	7	—	
			Negative rail	+25°C	—	8	—	
		V _O = 0.5V from rail, V _{DD} = 10V	Positive rail	+25°C	—	13	—	
			Negative rail	+25°C	—	12	—	
Power Supply								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
I _{DD}	Supply Current (per op-amp)	V _O = V _{DD} /2	V _{DD} = 2.7V	+25°C	—	470	560	μA
			V _{DD} = 5V	+25°C	—	550	660	
			V _{DD} = 10V	+25°C	—	625	800	
				-40°C to +125°C	—	—	1000	
I _{IB}	Power Supply Rejection Ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7V to 16V, V _{IC} = V _{DD} /2, No load		+25°C	70	80	—	dB
				-40°C to +125°C	65	—	—	

Electrical Characteristics (cont.) (@T_A = +25°C and V_{DD} = 2.7V, 5V, ±5V unless otherwise specified.)

Dynamic Performance								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
UGBW	Unity Gain Bandwidth	R _L = 2kΩ, C _L = 10pF	V _{DD} = 2.7V	+25°C	—	1.7	—	MHz
			V _{DD} = 5V to 10V	+25°C	—	1.9	—	
SR	Slew Rate At Unity Gain	V _{O(PP)} = V _{DD} /2, C _L = 50pF, R _L = 10kΩ	V _{DD} = 2.7V	+25°C	1.2	2.1	—	V/μs
				-40°C to +125°C	1	—	—	
			V _{DD} = 5V	+25°C	1.25	2.0	—	
				-40°C to +125°C	1.05	—	—	
			V _{DD} = 10V	+25°C	1.3	2.2	—	
				-40°C to +125°C	1.1	—	—	
Φ _m	Phase Margin	R _L = 2kΩ, C _L = 10pF		+25°C	—	65°C	—	—
	Gain Margin	R _L = 2kΩ, C _L = 10pF		+25°C	—	12	—	dB
t _s	Settling Time	V _{DD} = 2.7V, V _{(STEP)PP} = 1V, A _V = -1, C _L = 10pF, R _L = 2kΩ	0.1%	+25°C	—	2.9	—	μs
		V _{DD} = 5V, ±5V V _{(STEP)PP} = 1V, A _V = -1, C _L = 47pF, R _L = 2kΩ	0.1%	+25°C	—	2	—	
Noise/Distortion Performance								
Parameter		Conditions		T _A	Min	Typ	Max	Unit
THD+N	Total Harmonic Distortion Plus Noise	V _{DD} = 2.7V, V _{O(PP)} = V _{DD} /2, R _L = 2kΩ, f = 10kHz	A _V = 1	+25°C	—	0.02	—	%
			A _V = 10	+25°C	—	0.05	—	
			A _V = 100	+25°C	—	0.18	—	
		V _{DD} = 5V, ±5V V _{O(PP)} = V _{DD} /2, R _L = 2kΩ, f = 10kHz	A _V = 1	+25°C	—	0.02	—	
			A _V = 10	+25°C	—	0.09	—	
			A _V = 100	+25°C	—	0.5	—	
V _n	Equivalent Input Noise Voltage	f = 1kHz		+25°C	—	35	—	nV/√Hz
		f = 10kHz		+25°C	—	25	—	
I _n	Equivalent Input Noise Current	f = 1kHz		+25°C	—	0.6	—	fA/√Hz

Typical Performance Characteristics

List of Figures			
			Figure
V_{IO}	Input Offset Voltage	vs. free air temperature	1
I_{IB}, I_{IO}	Input Bias Current, Input Offset Current	vs. free air temperature	2
I_{DD}	Supply Current	vs. supply voltage	3
PSRR	Power Supply Rejection Ratio	vs. frequency	4
		vs. free air temperature	5
CMRR	Common Mode Rejection Ratio	vs. frequency	6
		vs. free air temperature	7
V_{OH}	High Level Output Voltage	vs. high level output current	8, 9, 10
V_{OL}	Low Level Output Voltage	vs. high level output current	11, 12, 13
SR	Slew Rate	vs. free air temperature	14
		vs. supply voltage	15
A_{VD}, Φ	Differential Voltage Gain And Phase	vs. frequency	16
Φ_m	Phase Margin	vs. capacitive load	17
—	Gain Bandwidth Product	vs. free air temperature	18
V_n	Equivalent Input Noise Voltage	vs. frequency	19
$V_{O(PP)}$	Peak To Peak Output Voltage	vs. frequency	20
—	Voltage Follower Large Signal Pulse Response	—	21, 22
—	Voltage Follower Small Signal Pulse Response	—	23
—	Inverting Large Signal Response	—	24, 25
—	Inverting Small Signal Response	—	26
—	Crosstalk	vs. frequency	27

Typical Performance Characteristics (cont.)

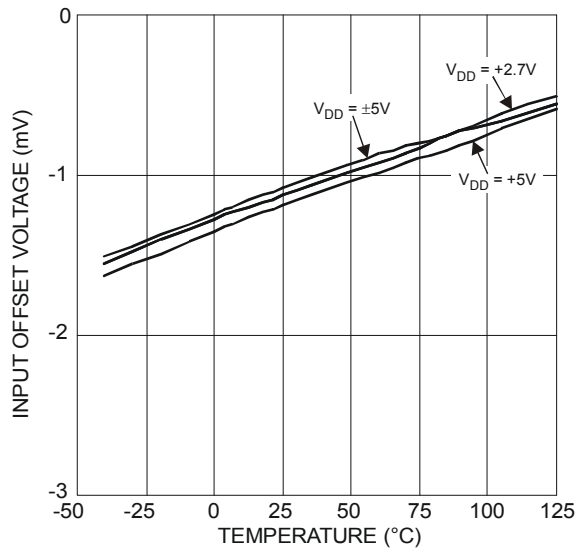


Figure 1 Input Offset Voltage vs. Temperature

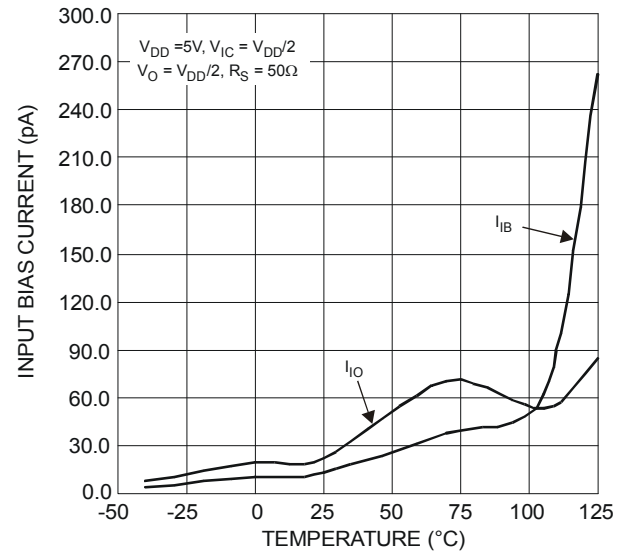


Figure 2 Input Bias and Offset Current vs. Temperature

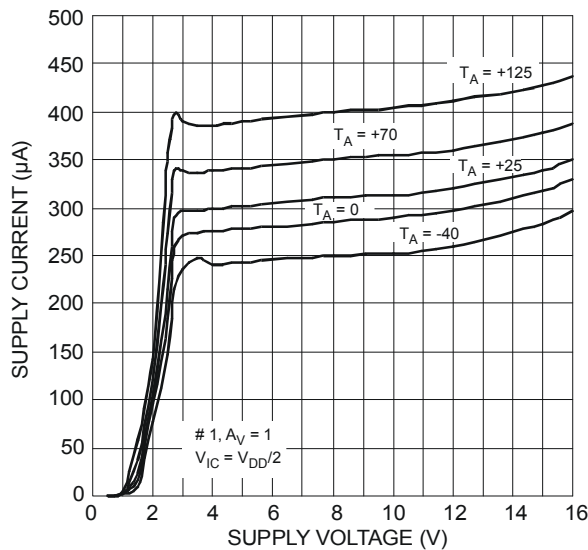


Figure 3 Supply Current vs. Supply Voltage

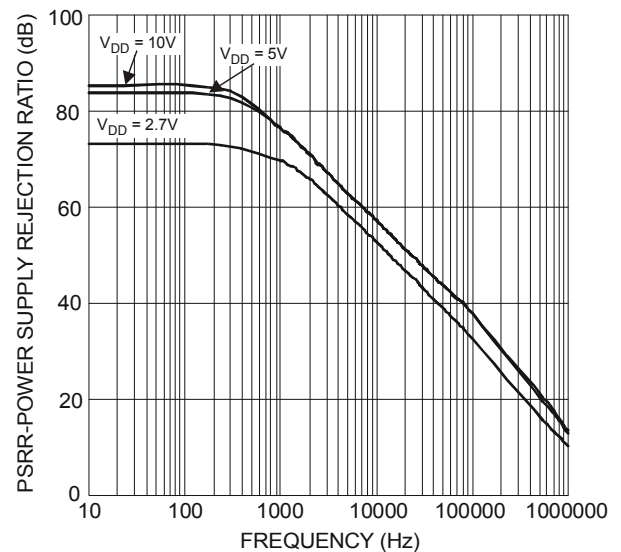


Figure 4 Power Supply Rejection Ratio vs. Frequency

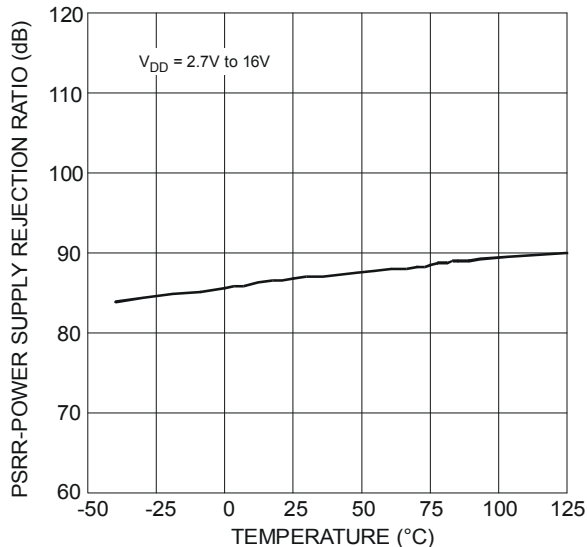


Figure 5 Power Supply Rejection Ratio vs. Temperature

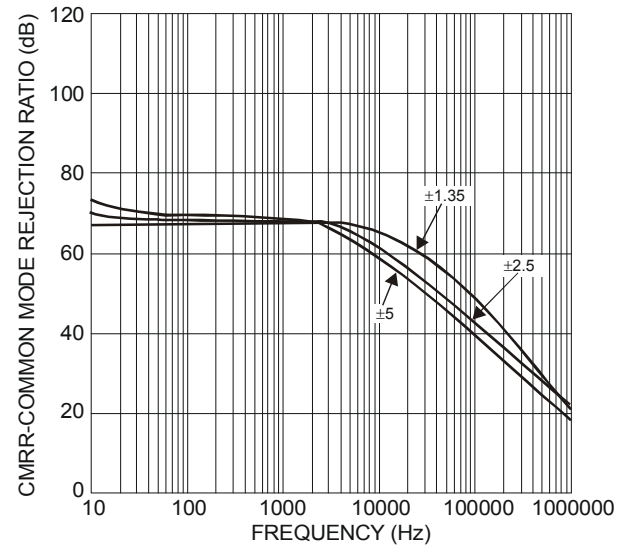


Figure 6 Common Mode Rejection Ratio vs. Frequency

Typical Performance Characteristics (cont.)

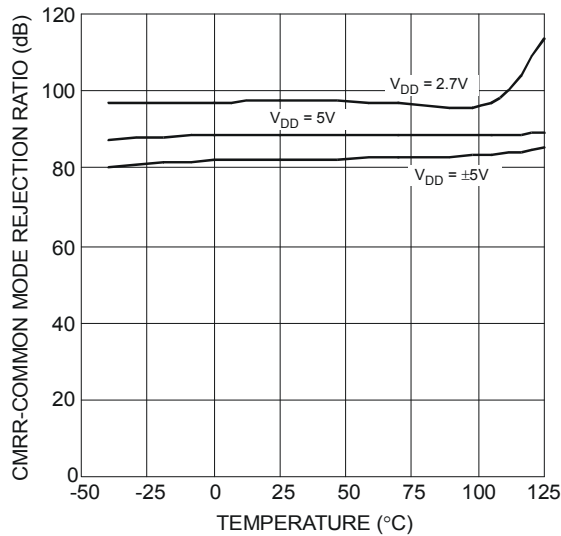


Figure 7 Common Mode Rejection Ratio vs. Temperature

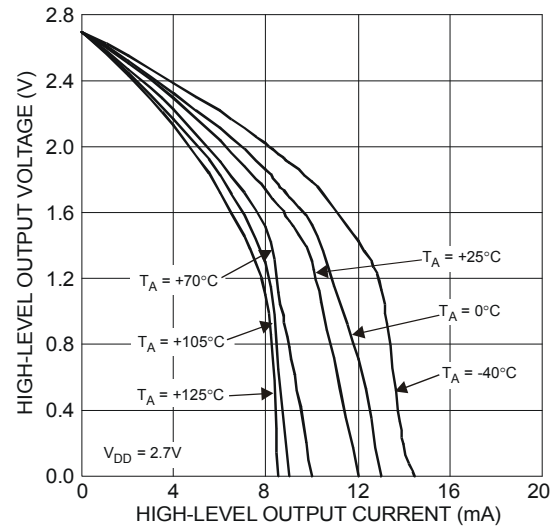


Figure 8 High-Level Output Voltage vs. High-Level Output Current

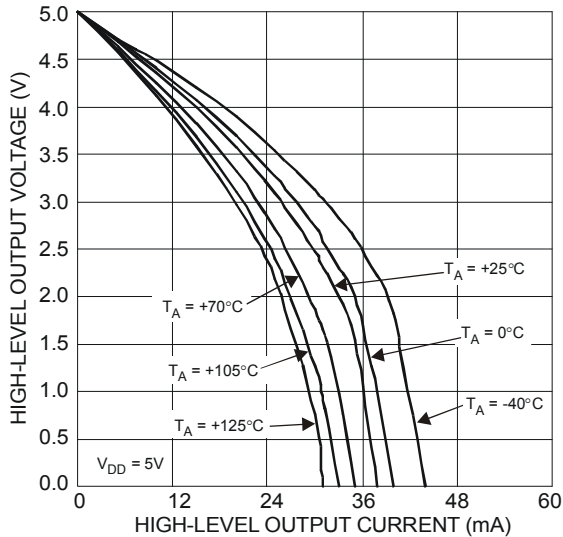


Figure 9 High-Level Output Voltage vs. High-Level Output Current

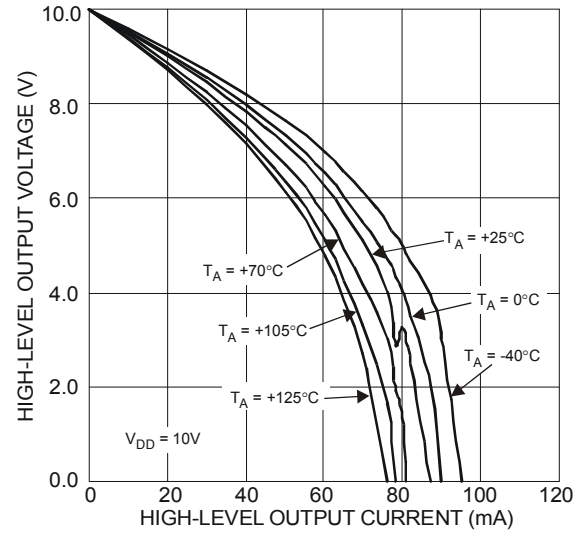


Figure 10 High-Level Output Voltage vs. High-Level Output Current

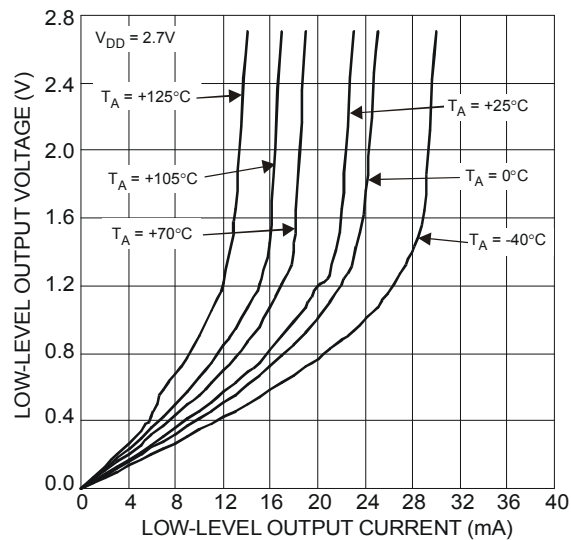


Figure 11 Low-Level Output Voltage vs. Low-Level Output Current

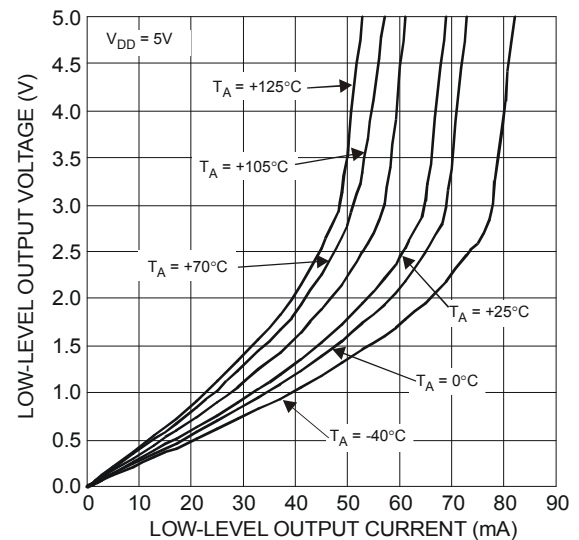


Figure 12 Low-Level Output Voltage vs. Low-Level Output Current

Typical Performance Characteristics (cont.)

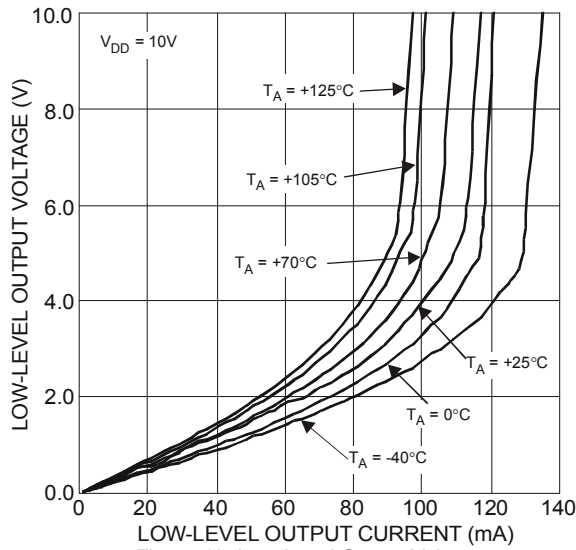


Figure 13 Low-Level Output Voltage vs. Low-Level Output Current

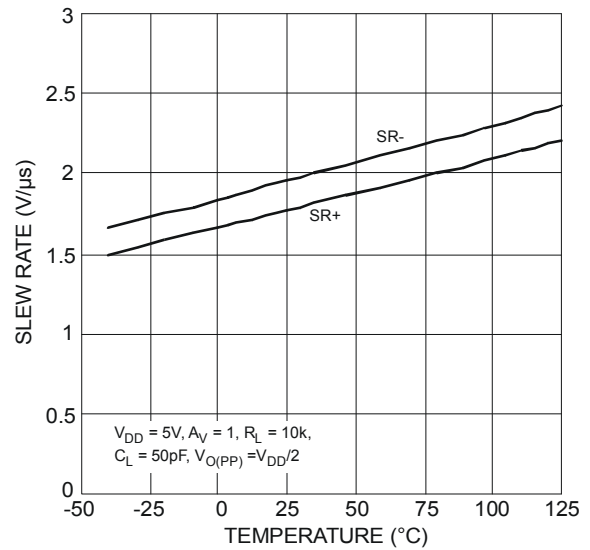


Figure 14 Slew Rate vs. Temperature

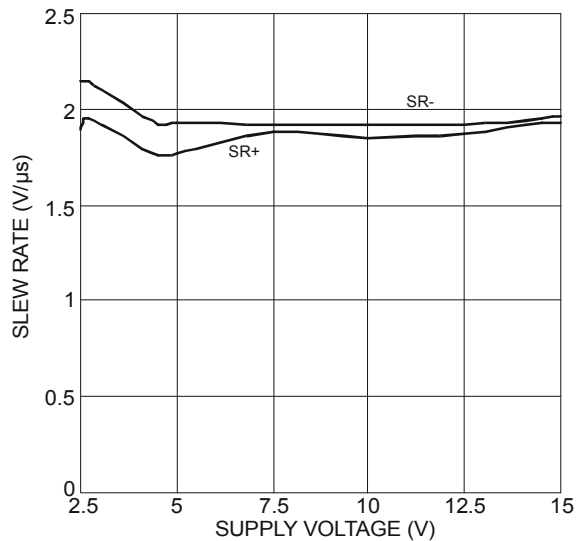


Figure 15 Slew Rate vs. Supply Voltage

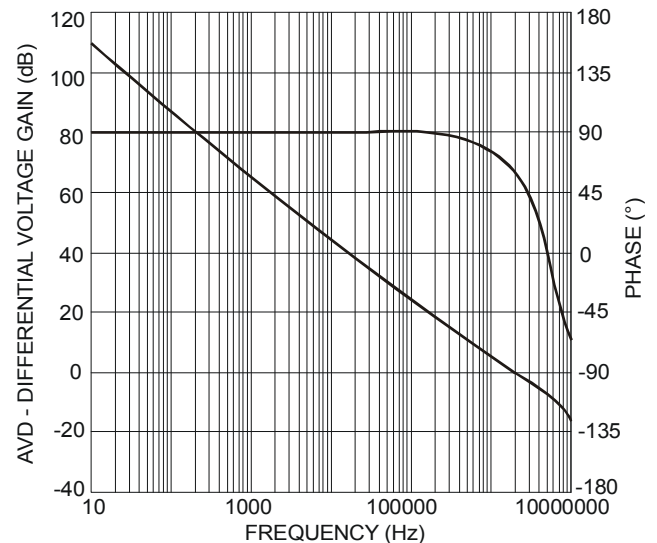


Figure 16 Differential Voltage Gain and Phase vs. Frequency

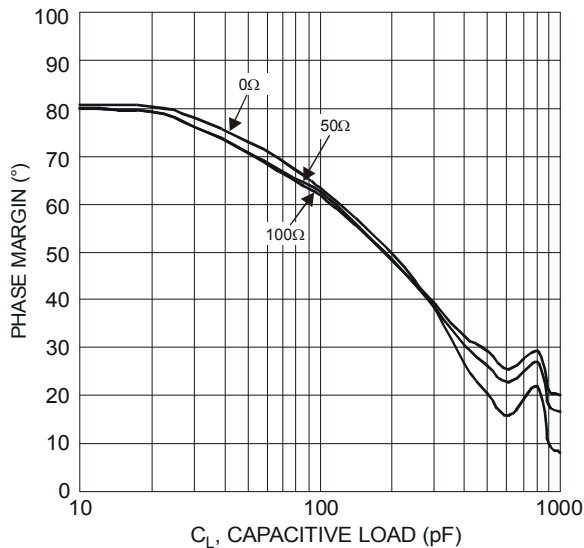


Figure 17 Phase Margin vs. Capacitive Load

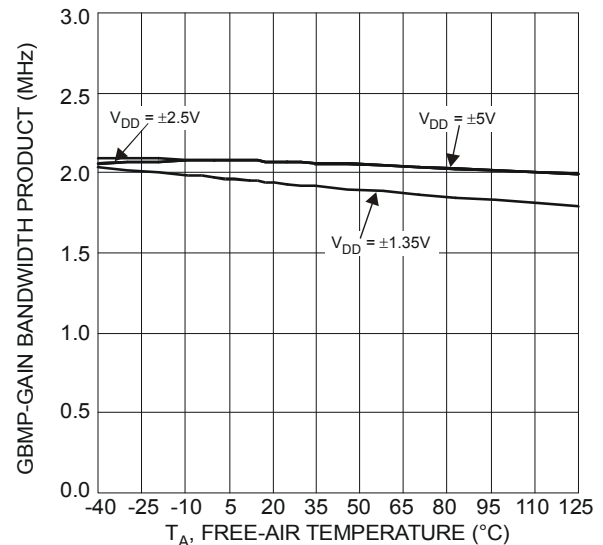


Figure 18 Gain Bandwidth Product vs. Free Air Temperature

Typical Performance Characteristics (cont.)

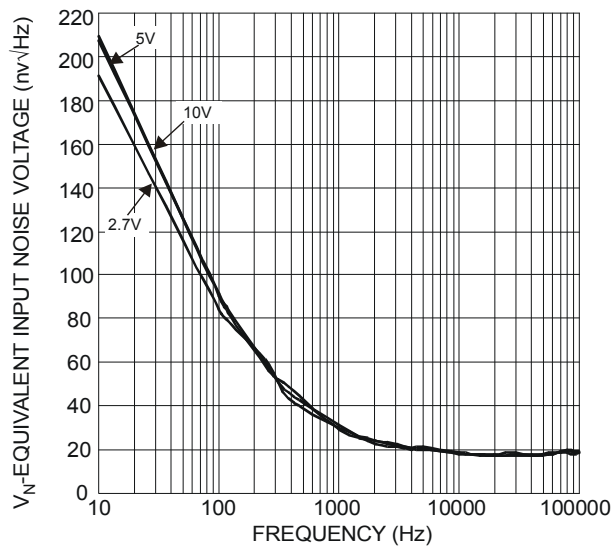


Figure 19 Equivalent Input Noise Voltage vs. Frequency

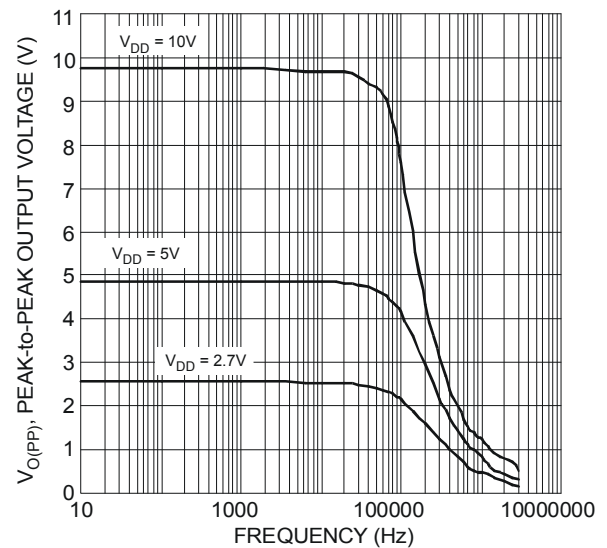


Figure 20 Peak-to-Peak Output Voltage vs. Frequency

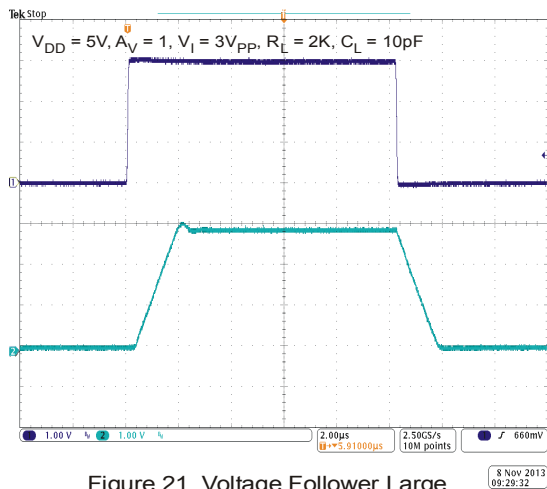


Figure 21 Voltage Follower Large Signal Pulse Response $V_{DD} = 5V$

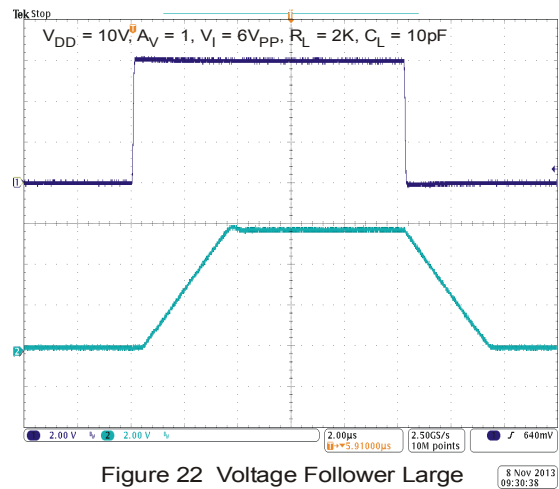


Figure 22 Voltage Follower Large Signal Pulse Response $V_{DD} = 10V$

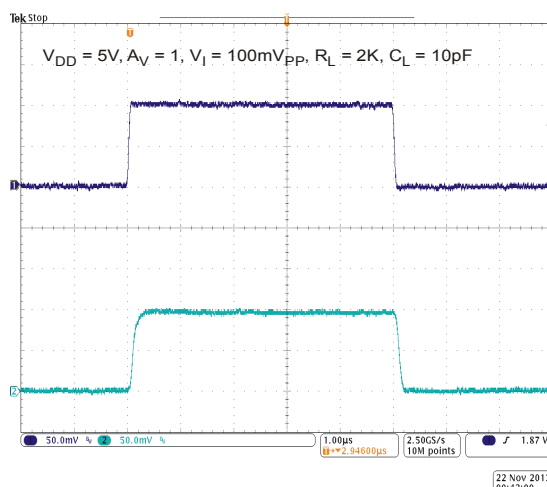


Figure 23 Voltage Follower Small Signal Pulse Response

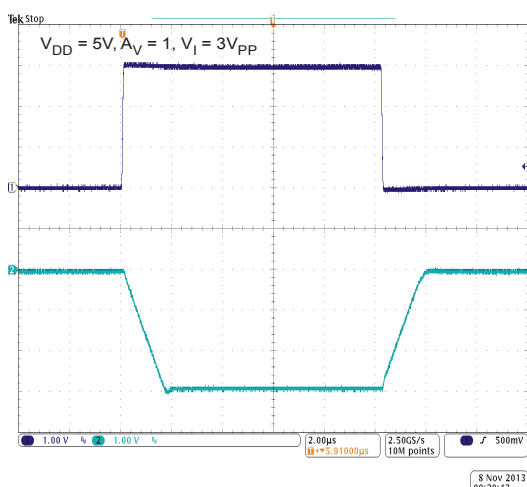


Figure 24 Inverting Large Signal Pulse Response $V_{DD} = 5V$

Typical Performance Characteristics (cont.)

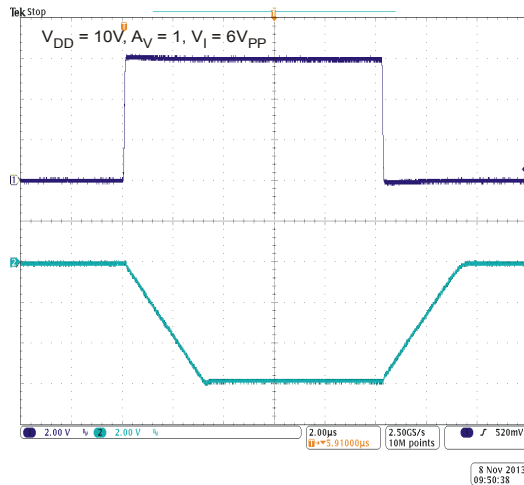


Figure 25 Inverting Large Signal Pulse Response $V_{DD} = 10V$

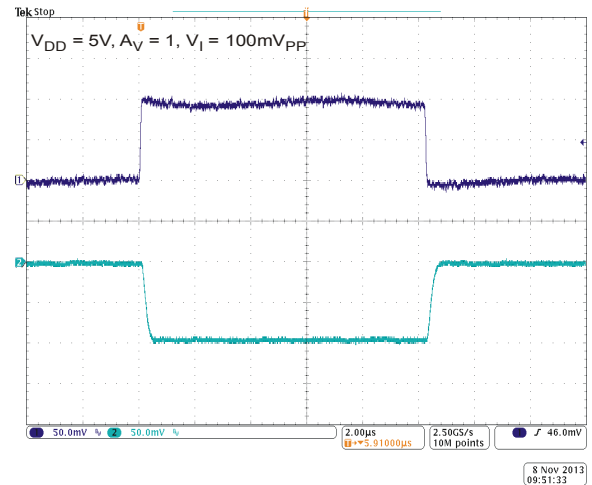


Figure 26 Inverting Small Signal Pulse Response

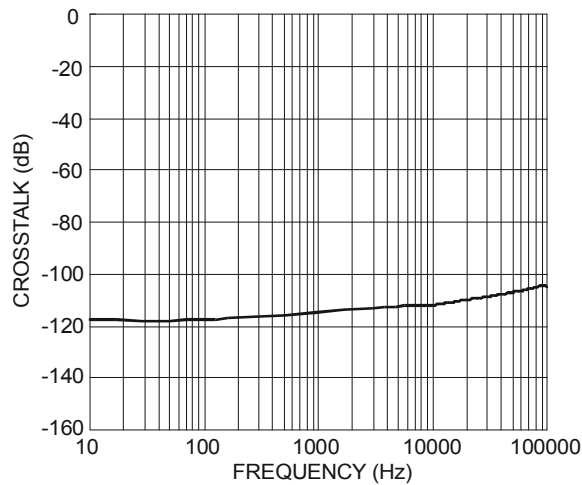


Figure 27 Crosstalk vs. Frequency TLV272

Application Information

Driving a Capacitive Load

When the amplifier is configured as below, capacitive loading directly on the output can decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 100pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 25. A minimum value of 20Ω should work well for most applications.

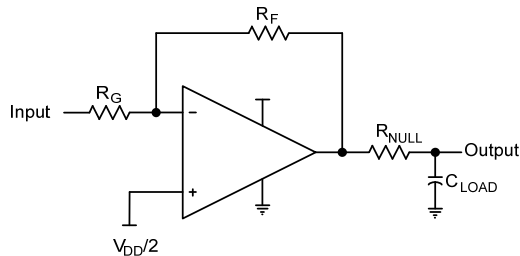


Figure 28 Driving a Capacitive Load

Offset Voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

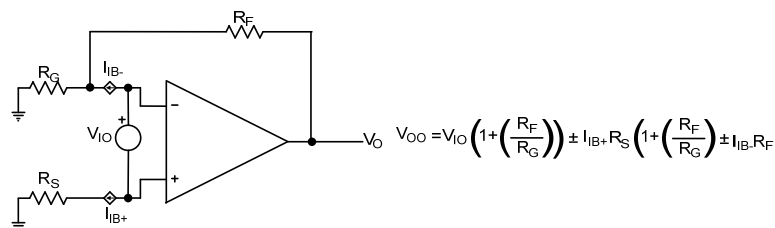


Figure 29 Output Offset Voltage Model

Other Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the non-inverting terminal of the amplifier (see Figure 30).

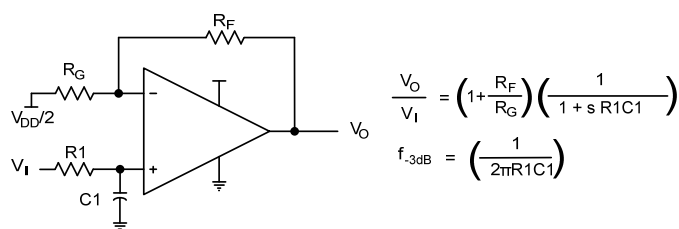


Figure 30 Single Pole Low Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

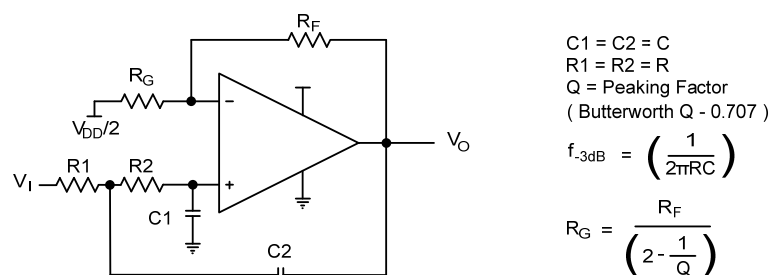
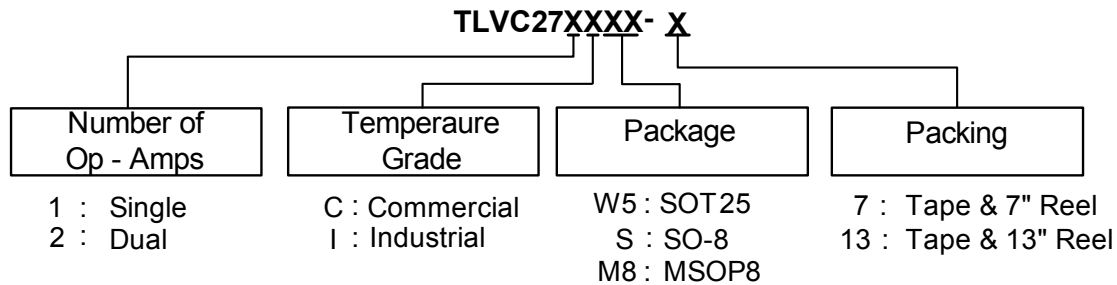


Figure 31 2-Pole Low-Pass Sallen-Key Filter

Ordering Information



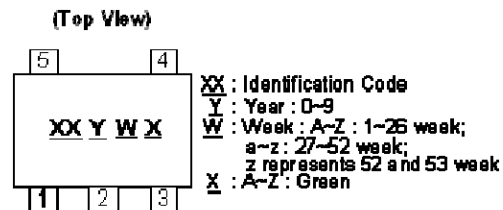
Part Number	Package Code	Operating Temperature Range	Packaging	7" or 13" Tape and Reel	
				Quantity	Part Number Suffix
TLV271CW5-7	W5	0 to +70°C	SOT25	3000/Tape & Reel	-7
TLV271CS-13**	S	0 to +70°C	SO-8	2500/Tape & Reel	-13
TLV271IW5-7	W5	-40°C to +125°C	SOT25	3000/Tape & Reel	-7
TLV271IS-13**	S	-40°C to +125°C	SO-8	2500/Tape & Reel	-13
TLV272CS-13**	S	0 to +70°C	SO-8	2500/Tape & Reel	-13
TLV272CM8-13**	M8	0 to +70°C	MSOP-8	2500/Tape & Reel	-13
TLV272IS-13**	S	-40°C to +125°C	SO-8	2500/Tape & Reel	-13
TLV272IM8-13**	M8	-40°C to +125°C	MSOP-8	2500/Tape & Reel	-13

**Future Products

Marking Information

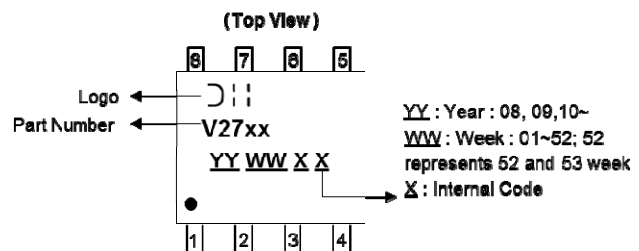
SOT25

Part mark	Part number
BV	TLV271CW5
BW	TLV271IW5



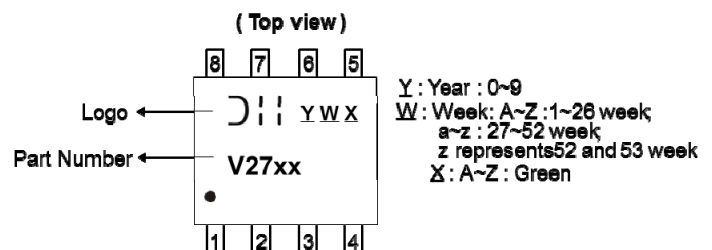
SO-8

Part mark	Part number
V271C	TLV271CS
V271I	TLV271IS
V272C	TLV272CS
V272I	TLV272IS



MSOP-8

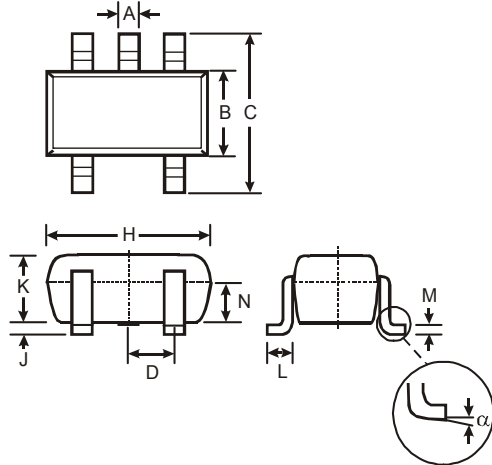
Part mark	Part number
V272C	TLV272CM8
V272I	TLV272IM8



Package Outline Dimensions (All dimensions in mm.)

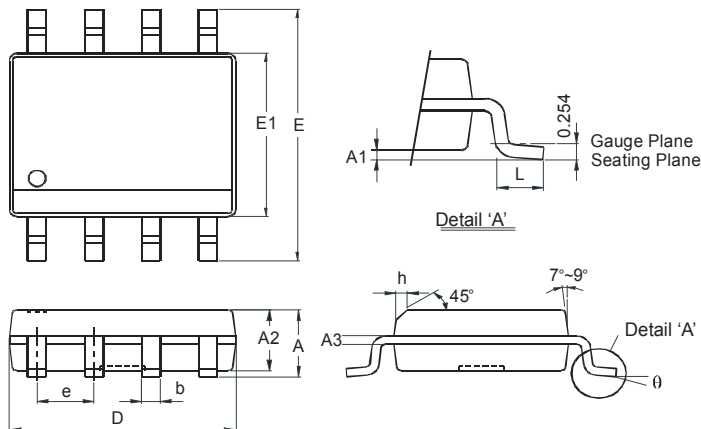
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

SOT25



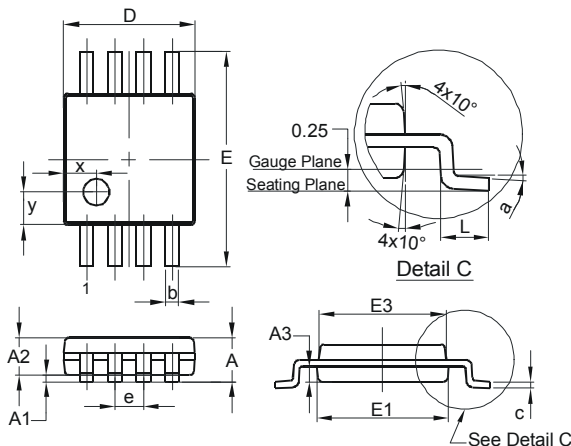
SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	—
All Dimensions in mm			

SO-8



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

MSOP-8

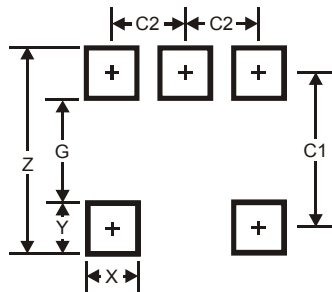


MSOP-8			
Dim	Min	Max	Typ
A	-	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
c	0.08	0.23	0.15
D	2.90	3.10	3.00
E	4.70	5.10	4.90
E1	2.90	3.10	3.00
E3	2.85	3.05	2.95
e	-	-	0.65
L	0.40	0.80	0.60
a	0°	8°	4°
x	-	-	0.750
y	-	-	0.750
All Dimensions in mm			

Suggested Pad Layout

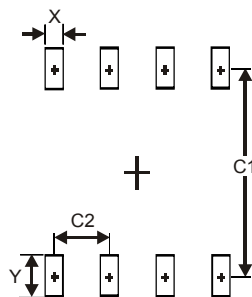
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

SOT25



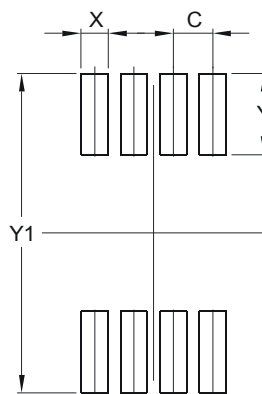
Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

SO-8



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

MSOP-8



Dimensions	Value (in mm)
C	0.650
X	0.450
Y	1.350
Y1	5.300

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